

CLAIM AMENDMENTS

CLAIMS

What is claimed is:

1 - 2. (CANCELED)

3. (CANCELED)

4. (CANCELED)

5. (PREVIOUSLY PRESENTED): A process tolerant sensor apparatus comprising:
- a) a bottom substrate;
 - b) a top substrate;
 - c) a plurality of sensors disposed between the bottom substrate and the top substrate;
 - d) a plurality of electrically conductive interconnects disposed between the bottom substrate and the top substrate;
 - e) electrically active components connected to the conductive interconnects for at least one of data acquisition, data storage, and communications; and
 - f) a bonding material substantially filling the volume between the bottom substrate and the top substrate,

wherein the bonding material is configured as a layer having a thickness between 0.05 mm and 10 mm.

6 - 15. (CANCELED)

16. (PREVIOUSLY PRESENTED): A process tolerant sensor apparatus comprising:
- a) a bottom substrate;

- b) a top substrate comprising an RF shielding material, the RF shielding material comprising at least one of
 - an electrically conductive layer comprising at least one of silver, nickel, aluminum, and carbon, and
 - a magnetically permeable film or layer comprising at least one of iron and cobalt;
- c) a plurality of sensors disposed between the bottom substrate and the top substrate;
- d) a plurality of electrically conductive interconnects disposed between the bottom substrate and the top substrate;
- e) electrically active components connected to the conductive interconnects for at least one of data acquisition, data storage, and communications; and
- f) a bonding material substantially filling the volume between the bottom substrate and the top substrate.

17. (PREVIOUSLY PRESENTED): A process tolerant sensor apparatus comprising:

- a) a bottom substrate;
- b) a top substrate;
- c) a plurality of sensors disposed between the bottom substrate and the top substrate;
- d) a plurality of electrically conductive interconnects disposed between the bottom substrate and the top substrate;
- e) electrically active components connected to the conductive interconnects for at least one of data acquisition, data storage, and communications; and
- f) a bonding material substantially filling the volume between the bottom substrate and the top substrate;

wherein the bottom substrate is selected from the group consisting of semiconductor wafer substrate, lithography mask substrate, printed circuit board substrate, and flat panel display substrate and the top substrate is selected from the group consisting of semiconductor wafer substrate, lithography mask substrate, printed circuit board substrate, and flat panel display substrate.

18 – 21. (CANCELED)

22. (PREVIOUSLY PRESENTED): The sensor apparatus of claim 5, wherein the top substrate comprises a silicon wafer.

23. (PREVIOUSLY PRESENTED): The sensor apparatus of claim 5, wherein the bonding material comprises a polymeric material selected from the group consisting of silicone, epoxy, acrylic, polyimide, polyurethane, and butyl rubber.

24. (PREVIOUSLY PRESENTED): The sensor apparatus of claim 5, wherein the top substrate comprises an RF shielding material.

25. (PREVIOUSLY PRESENTED): The sensor apparatus of claim 24, wherein the RF shielding material comprises at least one of:

- a) an electrically conductive layer and
- b) a magnetically permeable layer.

26. (PREVIOUSLY PRESENTED): The sensor apparatus of claim 25, wherein the shielding material includes layers patterned so as to enhance the shielding efficiency over predetermined frequency ranges.

27. (PREVIOUSLY PRESENTED): The sensor apparatus of claim 5, wherein at least one of the bottom substrate and the top substrate is thinned so that the thickness of the sensor apparatus substantially equals the thickness of a predetermined workpiece.

28. (PREVIOUSLY PRESENTED): The sensor apparatus of claim 5, wherein:
the plurality of sensors and electrically conductive interconnects are disposed upon the surface of the bottom substrate,
a mirror image pattern of the sensors and interconnects is disposed upon the surface of the top substrate, and

wherein the mirror image pattern and the sensors are of substantially the same thickness.

29. (PREVIOUSLY PRESENTED): The sensor apparatus of claim 5, wherein at least one of the electrically active components is disposed upon the surface of the bottom substrate, the top substrate has a hole, and the at least one of the electrically active components extends into the hole in the top substrate.

30. (PREVIOUSLY PRESENTED): The sensor apparatus of claim 5, wherein the bottom substrate is electrically isolated from the top substrate.

31. (PREVIOUSLY PRESENTED): The sensor apparatus of claim 5, wherein the bottom substrate is electrically connected to the top substrate.

32. (PREVIOUSLY PRESENTED): The sensor apparatus of claim 24, wherein the RF shielding material comprises at least one of

- a) an electrically conductive layer and
- b) a magnetically permeable layer.

33. (PREVIOUSLY PRESENTED): The sensor apparatus of claim 5, wherein the bottom substrate comprises a semiconductor wafer substrate and the top substrate comprises a semiconductor wafer substrate.

34. (PREVIOUSLY PRESENTED): The sensor apparatus of claim 5, wherein the bottom substrate comprises a lithography mask substrate and the top substrate comprises a lithography mask substrate.

35. (PREVIOUSLY PRESENTED): The sensor apparatus of claim 5, wherein the bottom substrate comprises a printed circuit board substrate and the top substrate comprises a printed circuit board substrate.

36. (PREVIOUSLY PRESENTED): The sensor apparatus of claim 5, wherein the bottom substrate comprises a flat panel display substrate and the top substrate comprises a flat panel display substrate.

37. (PREVIOUSLY PRESENTED): The sensor apparatus of claim 5, wherein the plurality of sensors comprises a plurality of temperature sensors.

38. (PREVIOUSLY PRESENTED): The sensor apparatus of claim 5 further comprising an electronics module comprising a housing containing electrically active components connected to the conductive interconnects.